PNZ108CL (PN108CL)

Silicon planar type

For optical control systems

Features

- High sensitivity: $I_L = 3.5 \text{ mA} \text{ (min.)}$
- Narrow directivity characteristics for effective use of light input
- Fast response: $t_r = 5 \ \mu s$ (typ.)
- Signal mixing capability using base pin
- Small size (low in height) package

Absolute Maximum Ratings $T_a = 25^{\circ}C$

| Parameter | Symbol Rating | | Unit | |
|---------------------------------------|------------------|-------------|------|--|
| Collector-emitter voltage (Base open) | V _{CEO} | 20 | V | |
| Collector-base voltage (Emitter open) | V _{CBO} | 30 | V | |
| Emitter-collector voltage (Base open) | V _{ECO} | 3 | V | |
| Emitter-base voltage (Collector open) | V _{EBO} | 5 | V | |
| Collector current | I _C | 20 | mA | |
| Collector power dissipation | P _C | 100 | mW | |
| Operating ambient temperature | T _{opr} | -25 to +85 | °C | |
| Storage temperature | T _{stg} | -30 to +100 | °C | |

Electrical-Optical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

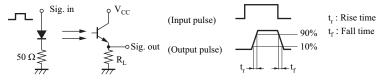
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------------------|---|-------|------|-----|------|
| Photocurrent *1 | IL | $V_{CE} = 10 \text{ V}, L = 500 \text{ lx}$ | 3.5 | | | mA |
| Collector-emitter cutoff current (Base open) | I _{CEO} | $V_{CE} = 10 V$ | allor | 0.05 | 2.0 | μΑ |
| Collector-emitter saturation voltage *1 | V _{CE(sat)} | $I_L = 1 \text{ mA}, L = 1000 \text{ lx}$ | 20 | 0.3 | 0.6 | V |
| Peak sensitivity wavelength | λ_{PD} | $V_{CE} = 10 V$ | | 900 | | nm |
| Half-power angle | θ | The angle when the photocurrent is halved | | 80 | | o |
| Rise time *2 | t _r | N 10.11 5 A D 100.0 | | 5 | | μs |
| Fall time *2 | t _f | $V_{\rm CC} = 10 \text{ V}, \text{ I}_{\rm L} = 5 \text{ mA}, \text{ R}_{\rm L} = 100 \Omega$ | | 6 | | μs |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. Spectral sensitivity characteristics: Sensitivity for wave length over 400 nm maximum sensitivity ratio is 100%.

- 3. This device is designed by disregarding radiation.
- 4. *1:Source: Tungsten lamp (color temperature 2 856K)

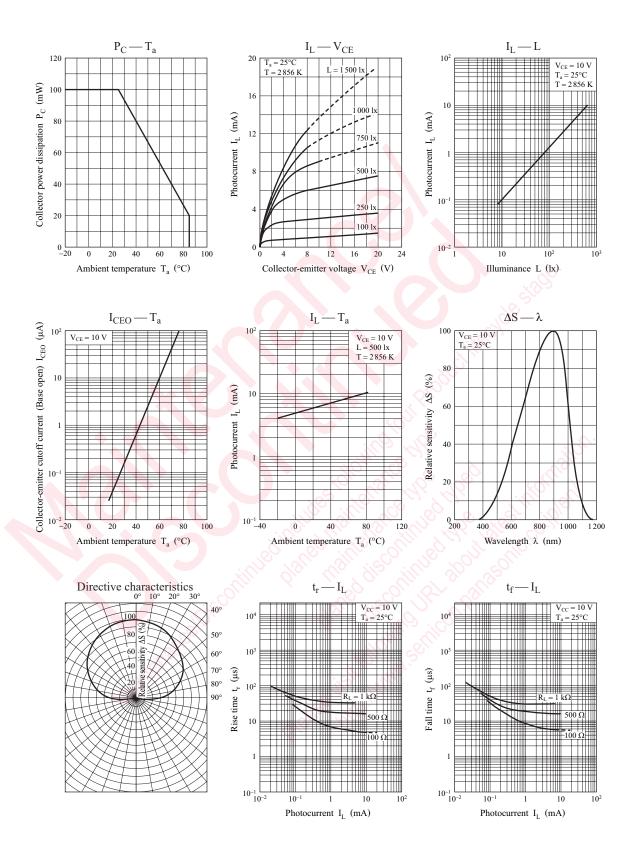
*2: Switching time measurement circuit



Note) The part number in the parenthesis shows conventional part number.

PNZ108CL

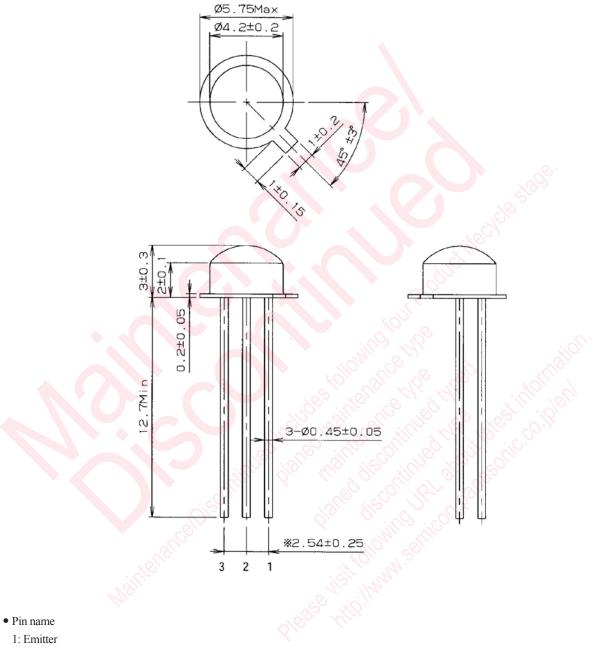
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Package (Unit: mm)





2: Base

3: Collector

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